SPC1 Series (1 kA)



Description

The SPC1 in SMTO-218 package provide the enhanced quality, easy manufacturing than typical through-hole TVS components. They can be connected in series and/or parallel to create various capability and flexible protection solutions.

Applications

- Communication Equipment
- Security & Protection
- Industrial Control Equipment
- Power Supply
- Automotive Electronics
- New Energy
- Lightning Protection

Functional Diagram



Bi-Directional

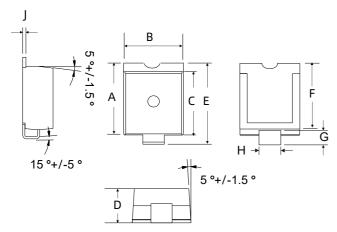
Features

- Bi-directional
- Low clamping and slope resistance
- For automatic pick and place assembly and reflow process to reduce the manufacturing cost and increase the soldering quality compared to axial leads package
- Patent pending package design
- Meet MSL level 1, per J-STD-020, LF Maximum peak of 245 °C
- Pb-free E3 means 2nd level interconnect is Pb-free and the terminal finish material is tin (Sn)
- ESD follow IEC 61000-4-2
- Surge protection of lightning in accordance with IEC61000-4-5
- Halogen free and RoHS compliant
- Tube or tape and reel pack options available

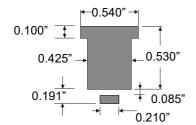
SPC1 Series (1 kA)

Transient Voltage Suppression Diodes

Package Outline Dimensions (SMTO-218)



Note: Coplanarity of solder side is controlled within 0.10 mm



Mounting Pad Layout (Inch)

0hl	Millim	eters	Inches				
Symbol	Min.	Max.	Min.	Max.			
А	15.78	16.63	0.621	0.655			
В	13.43	15.09	0.529	0.594			
С	13.83	14.24	0.544	0.561			
D	6.94	7.24	0.273	0.285			
E	17.82	18.72	0.702	0.737			
F	14.40	14.76	0.567	0.581			
G	1.88	2.84	0.074	0.112			
Н	4.89	5.65	0.193	0.222			
J	0.72	0.85	0.028	0.033			

Maximum Ratings and Characteristics

(Ratings at 25 °C ambient temperature unless otherwise specified.)

Parameter	Symbol	Value	Unit
Storage Temperature Range	T _{STG}	-55 to 150	°C
Operating Junction	TJ	-55 to 125	°C
Current Rating (8/20 µs wave)	I _{PP}	1	kA

Physical Specifications

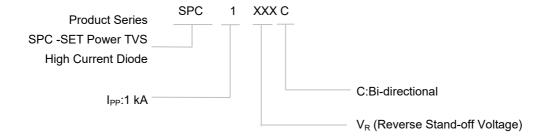
Weight	Contact manufacturer
Case	Epoxy molding compound encapsulated
Terminal	Tin plated lead, solderability per MIL-STD-202 Method 208



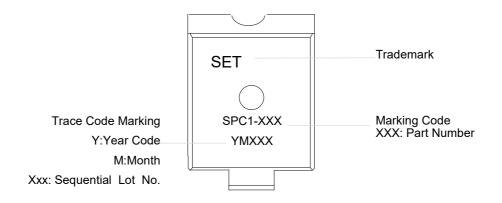
Environmental Specifications

Temperature Cycling	JESD22-A104					
HTRB	JESD22-A108					
MSL	JESDEC-J-STD-020, Level 1					
H3TRB	JESD22-A101					
RSH	JESD22-B106					

Part Numbering System



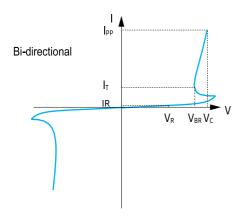
Marking



Electrical Characteristics (T_A=25 °C unless otherwise noted)

Part Number	Stand-off Voltage	Max. Reverse	Vol	down tage	Test Current			,		Max. Capacitance		
	V _R	Leakage I _R @V _R	Max		V _{BR} @I₁ Min Max		I _T	V _{CL}	I _{PP} (8/20 μs)	Ι _{ΡΡ} (10/350 μs)	of V _{BR}	0 Bias 10KHz
			Min	Max			Min	Typical				
	(V)	(μΑ)	((V)		(V)	(A)	(A)	(%/°C)	(nF)		
SPC1-380C	380	10	401 443		10	520	1000	100	0.1	2.2		
SPC1-430C	430	10	440	490	10	625	1000	100	0.1	2.2		

I-V Curve Characteristics



Performance Curve for Reference(T_A=25 °C unless otherwise noted)

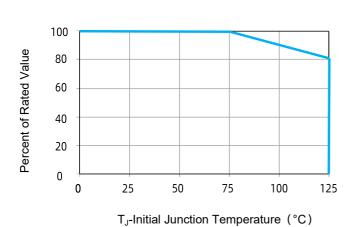


FIGURE 1 Peak Power Derating

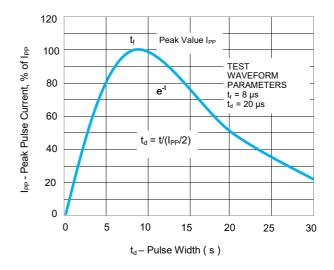
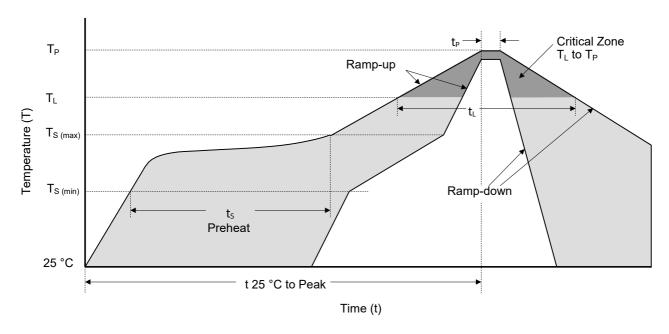


FIGURE 2 Pulse Waveform

Soldering Parameters



Reflowing Condition

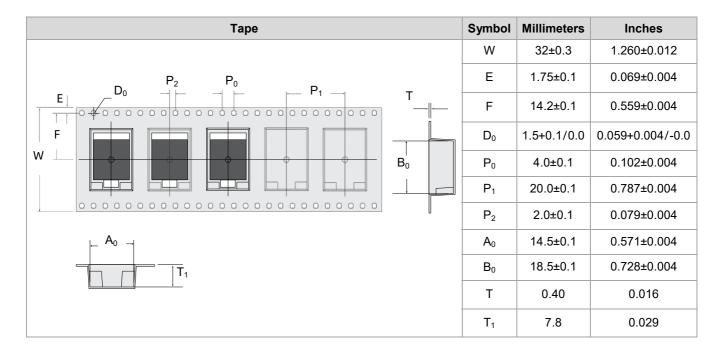
Reflow Soldering	ng Parameters	Lead-Free Assembly					
	Temperature Min (T _{S (min)})	150 °C					
Pre-heat	Temperature Max (T _{S (max)})	200 °C					
	Time (min to max) (t _s)	60 ~ 120 seconds					
Average Ramp Up Rate (L	Average Ramp Up Rate (Liquidus Temp (TL) to Peak						
T _S (max) to T _L	Ramp-up Rate	3 °C / second max.					
D. 6	Temperature (T _L) (Liquidus)	217 °C					
Reflow	Time (min to max) (t _L)	60 ~ 150 seconds					
Peak Tempo	erature (T _P)	245 ^{+0/-5} °C					
Time of within 5 °C of Act	ual Peak Temperature (t _P)	20 ~ 40 seconds					
Ramp-do	wn Rate	6 °C / second max.					
Time from 25 °C to	Time from 25 °C to Peak Temperature						
Do Not	245 °C						

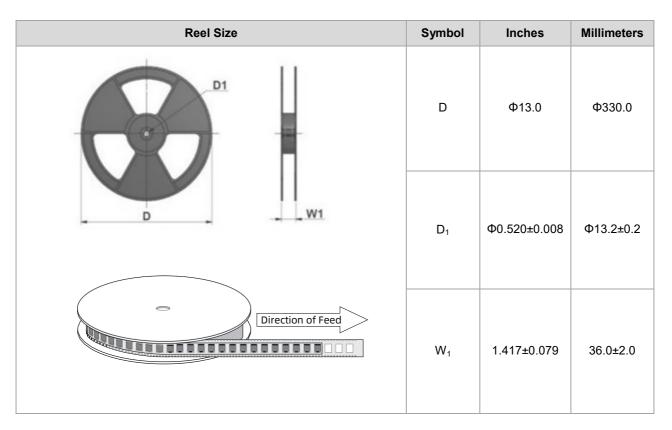
Wave Soldering (Solder Dipping)

Peak Temperature	260 °C+0 /- 5 °C
Dipping Time	10 seconds
Soldering Number	1 time

SPC1 Series (1 kA)

Packaging Information





Part Number	Weight (Typical)	Packaging Option	QTY's
SPC1-XXXXC	4.33 g	Tape & Reel – 32 mm/13" tape	400 PCS

SPC1 Series (1 kA)

Glossary

Item	Description
V _C	Clamping Voltage Voltage across TVS in a region of low differential resistance that serves to limit the voltage across the device terminals.
V _R	Reverse Stand-off Voltage Maximum voltage that can be applied to the TVS without operation. NOTE: It is also shown as V_{WM} (maximum working voltage (maximum d.c. voltage)) and known as rated stand-off voltage (V_{so}).
I _R	Reverse Leakage Current Current measured at V_R . NOTE : Also shown as I_D for stand-by current.
V BR	Breakdown Voltage Voltage across TVS at a specified current I_T in the breakdown region.
I _{PPM}	Rated Random Recurring Peak Impulse Current Maximum-rated value of random recurring peak impulse current that may be applied to a device.
P _{M(AV)}	Rated Average Power Dissipation Maximum-rated value of power dissipation resulting from all sources, including transients and standby current, averaged over a short period of time.
P _{PPM}	Rated Random Recurring Peak Impulse Power Dissipation Maximum-rated value of the product of rated random recurring peak impulse current (I_{PPM}) multiplies by specified maximum clamping voltage (V_{C}).
Сл	Capacitance Capacitance across the TVS measured at a specified frequency and voltage.
V _{FS}	Peak Forward Surge Voltage Peak voltage across an TVS for a specified forward surge current (I_{FS}) and time duration. NOTE: Also shown as V_{F} .
I _{FS}	Forward Surge Current Pulsed current through TVS in the forward conducting region. NOTE : Also shown as $I_{\rm F}$.
$a_{V(BR)}$	Temperature Coefficient of Breakdown Voltage The change of breakdown voltage divided by the change of temperature.
I _{PP}	Peak pulse Current Peak pulse current value applied across the TVS to determine the clamping voltage $V_{\mathbb{C}}$ for a specified wave shape.
I T	Pulsed D.C. Test Current Test current for measurement of the breakdown voltage V_{BR} . This is defined by the manufacturer and usually given in milliamperes with a pulse duration of less than 40 ms. NOTE: Also shown as I_{BR} .

-(GB-T 18802.321 / IEC 61643-321 / JESD210A)

SPC1 Series (1 kA)



Usage

- TVS must be operated in the specified ambient temp.
- Do not clean the TVS with strong polar solvent such as ketone, esters, benzene and halogenated hydrocarbon, to avoid damaging the encapsulating layer.
- 3. Please do not apply severe vibration, shock or pressure to TVS, to avoid element cracking.

Replacement

- If TVS is visually damaged, please replace it.
- TVS is a non-repairable product. For safety sake, please use equivalent TVS for replacement.

Storage

- 1. Storage Temp. Range: (-55 to 150) °C.
- Do not store the TVS at the high temp., high humidity or corrosive gas environment, to avoid influencing the solder- ability of the lead wires. The product shall be used up within 1 year after receiving the goods.

Environmental Conditions

- 1. TVS should not be exposed to the open air, nor direct sunshine.
- 2. TVS should avoid rain, water vapor or other condition of high temp. and high humidity.
- TVS should avoid sand dust, salt mist, or other harmful gases.

Max. Typical Capacitance of TVS

The typical capacitance of TVS is listed in the specifications. Designers may refer to it when designing TVS in High frequency circuit.

Installation Mechanical Stress

- 1. Do not knock TVS when installing, to avoid mechanical damage.
- 2. Please do not apply severe vibration, shock or pressure to TVS, to avoid surface resin or element cracking.

Transient Voltage Suppressor (Surface Mount) Features Overview

	1	\								/	\	
	DO-221AC	0	0	0	0	0	SMA6L	0	0	0		
be	DO-214AA	0	0	0	0	0	0	SACB	SMBJ	P6SMB		
Package Type	DO-214AB										Series	
ıckaç	DO-214AC	0	0	SMAJ	P4SMA	SMA6J	0	0	0	0	ies	
Ра	SOD-123FL	SMF	P4SMF									
	SMTO-218	0	0	0	0	0	0	0	0	0		
Proc	duct Outline (mm)	1.30	3.65		5.04		5.20 80 7	5.40				
V i Revers	R / V WM (V) e Stand-off Voltage	5.0 ~ 250	5.0 ~ 85	5.0 ~ 440	5.8 ~ 468	5.0 ~	250	5.0 ~ 50	5.0 ~ 440	5.8 ~ 512		
(10 Rate Po	PPPM (W) 0/1000 µs) ed Peak ImPulse wer Dissipation	200		400		600 500 600						
PPM (Rated P	kA)(8/20 µs) eak ImPulse Current					0						
C Te	perating mperature (°C)	-55 to +150										

SPC1 Series (1 kA)

TVS Diodes

Transient Voltage Suppression Diodes

	1	\								/	\	
	DO-221AC	0	0	0	0	0	0	0	0	0		
be	DO-214AA	0	0	0 0		0	0	0	0	0		
Je Ty	DO-214AB	SMCJ	1.5SMC	3.0SMCJ	SMDJ	5.0SMDJ					Series	
Package Type	DO-214AC	0	0	0	0	0	0	0	0	0	ies	
Ра	SOD-123FL	0		0					0			
	SMTO-218	0	0	0	0	0	SPC1	SPC3	SPC6	SPC10	\rightarrow	
Proc	duct Outline (mm)			7.94			18.27					
V F Revers	R / V _{WM} (V) e Stand-off Voltage	5.0 ~ 440	5.8 ~ 512	5.0 ~	- 440	12 ~ 170	380 / 430	66	58 ~ 76	58 ~ 86		
(10 Rate Por	P _{PPM} (W) 0/1000 μs) ed Peak ImPulse wer Dissipation	15	00	30	100	5000			0			
PPM (Rated P	(kA)(8/20 µs) eak ImPulse Current			0			1	3	6	10		
	perating mperature (°C)			-55 to +150		-55 to +125						

Transient Voltage Suppressor (Axial Lead) Features Overview

SPC1 Series (1 kA)

		\															\
	DO-201	0	0	0	1.5KE	LCE	0	0	0	0	0	0	0	0	0	0	
Гуре	DO-41	P4KE														0	(0
Package Type	DO-15	0	SAC	P6KE	0	0	0	0	0	0	0	0	0	0	0	0	Series
Pacl	P600	0					5KP	15KPA	20KPA	30KPA						0	•
Ra	idial lead	0	0	0	0	0	0	0	0	0	SPCL1	SPCL3	SPCL6	SPCL10	SPCL15	SPCL20	\rightarrow
	ct Outline nm)	9 ± 465 + 42.35 × 45 × 45 × 45 × 45 × 45 × 45 × 45 ×	Ф3.10 О С ©	57.50	Φ5.05	59.15		Φ8.85 98 80 Φ1.28	59.65		20.48	17.00	0	0.48	14.50	2.00	
V R / l Reverse Sta	WM (V) and-off Voltage	5.8 ~ 468	5.0 ~ 50	5.8 ~ 512	5.8 ~ 512	6.5 ~ 90	5.0 ~ 250	17 ~ 280	20 ~ 300	28 ~ 360	76	15 ~ 430	30 ~ 430	15 ~ 530	58 ~ 380	16 ~ 76	
PPP (10/10 Rated Pe Power D	PM (W) 000 µS) eak ImPulse Dissipation	400	500	600	15	00	5000	15000	20000	30000				0			
PPM (KA Rated Peak I	a)(8/20 µs) ImPulse Current	0							1	3	6	10	15	20			
Temp	erating perature °C)	-55 to +150										-55	to +125				